# Impedances of azimuthally symmetric irises and cavities with semielliptical profile in a beam pipe

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The beam coupling impedances of small axisymmetric obstacles having a semielliptical cross section along the beam in the vacuum chamber of an accelerator are calculated at frequencies for which the wavelength is large compared to a typical size of the obstacle. Analytical results are obtained for both the irises and the cavities with such a shape, which allows simple estimates of their broadband impedances. [S1063-651X(97)01003-9]

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### I. INTRODUCTION

High currents in modern accelerators and colliders severely restrict the allowed coupling impedance of the machine. For this reason, it is important to know the impedance contributions even from small discontinuities of the vacuum chamber.

In the preceding paper [1], Kurennoy has analytically calculated the low-frequency coupling impedance of small obstacles protruding into a beam pipe. In this paper we present an alternative derivation for an azimuthally symmetric semielliptical object protruding into a beam pipe, which confirms the dependence on the depth, but not on the width, of the protrusion. We also study the more difficult—from the analytical point of view—case of an axisymmetric semielliptical protrusion *outside* the beam pipe (cavity), and present variational results for different elliptical eccentricities.

#### **II. GENERAL ANALYSIS**

Consider a beam pipe of radius  $R_{pipe}$  and an azimuthally symmetric obstacle whose dimensions are small compared with both  $R_{pipe}$  and  $\lambda$ , the rf wavelength. We start with the definition of the longitudinal impedance as [2]

$$Z_{\parallel}(k) = \frac{1}{\left|I_{0}\right|^{2}} \int dv \mathbf{E} \cdot \mathbf{J}^{*}, \qquad (2.1)$$

where the current in the frequency domain for an ultrarelativistic point charge is

$$J_{z}(x,y,z;k) = I_{0}\delta(x)\delta(y)\exp(-jkz), \qquad (2.2)$$

with  $k = \omega/c = 2\pi/\lambda$ , and with the implied time dependence of all quantities being  $\exp(j\omega t)$ . We then identify two configurations: the subscript 1 denotes the pipe without the obstacle and the subscript 2 denotes the pipe with the obstacle. By forming the combination

$$-\int dv (\mathbf{E}_2 \cdot \mathbf{J}^* + \mathbf{E}_1^* \cdot \mathbf{J})$$

and using Maxwell's equations to write J in terms of the fields E and H, we write the contribution of the obstacle to the impedance as

$$|I_0|^2 Z_u(k) = \int_{S_2 \neq S_1} dS_2 \mathbf{n}_2 \cdot \mathbf{E}_1^* \times \mathbf{H}_2, \qquad (2.3)$$

where the surface integral is only over the surface of the obstacle. Using

$$E_{1r}^{*} = \frac{Z_0 I_0^{*}}{2 \pi r} \exp(jkz)$$
(2.4)

and

$$\mathbf{n}_2 dS_2 = 2 \pi r [\hat{\mathbf{n}} dz - \hat{\mathbf{z}} dr], \qquad (2.5)$$

with  $\hat{\mathbf{r}}$  and  $\hat{\mathbf{z}}$  being unit vectors, we have

$$\frac{Z_{\parallel}(k)}{Z_0} = -\frac{1}{I_0} \int dr H_{2\phi} e^{jkz}.$$
 (2.6)

Figure 1 shows the geometry for an obstacle protruding into and outside of the beam pipe.



FIG. 1. The beam pipe with an interior (a) and exterior (b) obstacle. One assumes  $a, b \ll Y, Z \ll \lambda, R_{\text{pipe}}$ .

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A more explicit form for Eq. (2.6) is

$$\frac{Z_{\parallel}(k)}{Z_{0}} = -\frac{1}{I_{0}} \left[ \int_{R_{\text{pipe}}}^{r_{1}} dr H_{2\phi}(r, z_{a}(r)) e^{jkz(r)} + \int_{r_{1}}^{R_{\text{pipe}}} dr H_{2\phi}(r, z_{b}(r)) e^{jkz(r)} \right].$$
(2.7)

We now convert the terms in square brackets in Eq. (2.7) to a double integral for the obstacle in Fig. 1(a):

$$\begin{bmatrix} \end{bmatrix} = \int_{r_1}^{R_{\text{pipe}}} \int_{-Z}^{z_a(r)} dz \frac{\partial}{\partial z} (H_{2\phi} e^{jkz}) + \int_{r_1}^{R_{\text{pipe}}} dr (H_{2\phi} e^{jkz}) \Big|_{z=-Z} + \int_{r_1}^{R_{\text{pipe}}} dr \int_{z_b(r)}^{Z} dz \frac{\partial}{\partial z} (H_{2\phi} e^{jzk}) - \int_{r_1}^{R_{\text{pipe}}} dr (H_{2\phi} e^{jkz}) \Big|_{z=Z}.$$

$$(2.8)$$

Here Z is a distance large compared with the dimensions of the obstacle, but small compared with  $\lambda$  and  $R_{pipe}$ , so that  $H_{2\phi}\exp(jkz)$  takes on its value in a pipe without an obstacle at  $z = \pm Z$ , namely,

$$H_{2\phi}(\pm Z) = I_0 \exp(\mp jkZ).$$
 (2.9)

This causes the second and fourth terms on the right side of Eq. (2.8) to cancel. We also add the vanishing term

$$\int_{R_{\rm pipe}^{-Y}}^{r_1} dr \int_{-Z}^{Z} dz \frac{\partial}{\partial z} (H_{2\phi} e^{jkz}), \qquad (2.10)$$

and finally obtain

$$\frac{Z_{\parallel}(k)}{Z_0} = \frac{1}{I_0} \int \int_{\text{solid}} dr dz \frac{\partial}{\partial z} (H_{2\phi} e^{jkz}), \qquad (2.11)$$

where the area of integration is within the solid border in Fig. 1(a). Parallel arguments lead to the same result for the obstacle in Fig. 1(b).

We now use Maxwell's equations to rewrite Eq. (2.11) as

$$\frac{Z_{\parallel}(k)}{Z_0} = -\frac{jk}{Z_0 I_0} \int \int_{\text{solid}} dr dz (E_r - Z_0 H_{\phi}) e^{jkz},$$
(2.12)

where we have dropped the subscript 2. For low frequency we set exp(jkz)=1 and obtain

$$\frac{Z_{\parallel}(k)}{Z_0} \simeq -\frac{jk}{Z_0 I_0} \int \int_{\text{solid}} dr dz (E_r - Z_0 H_{\phi}). \quad (2.13)$$

Clearly our derivation has resulted in a separation into a term involving the electric polarizability and a term involving the magnetic susceptibility (in the azimuthal direction) as in previous work [3–6]. Since the obstacles are azimuthally symmetric, we can replace  $Z_0H_{\phi}$  in the vicinity of the obstacle by

$$Z_0 H_{\phi} = E_0 = Z_0 I_0 / (2 \pi R_{\text{pipe}})$$
 (2.14)

and find

$$\frac{Z_{\parallel}(k)}{Z_0} = -\frac{jk}{2\pi R_{\text{pipe}}} \int \int_{\text{solid} \text{border}} dr dz \left(\frac{E_r - E_0}{E_0}\right). \quad (2.15)$$

#### **III. SEMIELLIPTICAL INTERIOR OBSTACLE-IRIS**

We now proceed to calculate Eq. (2.15) explicitly for the geometry of Fig. 1(a). We change from the variable r to the variable

$$y = R_{\rm pipe} - r, \qquad (3.1)$$

with  $|y| \ll \lambda$ ,  $|y| \ll R_{\text{pipe}}$ , and we use elliptical coordinates [7] defined by

$$y = c \cosh u \cos v$$
,  $z = c \sinh u \sin v$ ,

$$a = c \sinh u_0, \quad b = c \cosh u_0, \quad c^2 = b^2 - a^2.$$
 (3.2)

The metric (Jacobian) is defined by

$$dzdy = c^2 D(u,v) dudv, \qquad (3.3)$$

where

$$D(u,v) = \cosh^2 u \, \sin^2 v + \sinh^2 u \, \cos^2 v, \qquad (3.4)$$

and the Laplacian operator can be written as

$$\frac{\partial^2}{\partial x^2} + \frac{\partial^2}{\partial y^2} = \frac{1}{c^2 D(u,v)} \left( \frac{\partial^2}{\partial u^2} + \frac{\partial^2}{\partial v^2} \right).$$
(3.5)

The solution to Laplace's equation for the electrostatic potential in the region  $u \ge u_0$ , with  $\Psi(u_0, v) = 0$ , and with the asymptotic field  $E_0$ , is

$$\Psi(u,v) = cE_0 \cos \left[\cosh u - e^{u_0 - u} \cosh u_0\right], \quad (3.6)$$

where

$$E_r = -\frac{\partial \Psi}{\partial r} = \frac{\partial \Psi}{\partial y} = E_0 - cE_0 e^{u_0} \cosh u_0 \frac{\partial}{\partial y} (\cos v e^{-u}).$$
(3.7)

Here we choose  $\cos v$  in the second term to preserve the symmetry around v=0 (z=0), and to satisfy the boundary condition for all v at  $u=u_0$  and for  $v=\pm \pi/2$  with  $u \ge u_0$ . Also we have

$$\frac{\partial}{\partial y} = \frac{\partial u}{\partial y} \frac{\partial}{\partial u} + \frac{\partial v}{\partial y} \frac{\partial}{\partial v}$$
$$= \frac{1}{cD(u,v)} \left[ \sinh u \, \cos v \, \frac{\partial}{\partial u} - \cosh u \, \sin v \, \frac{\partial}{\partial v} \right]. \quad (3.8)$$

Applying this to Eq. (3.7) for  $E_r - E_0$ , we find from Eq. (3.6) that

$$=\frac{jkc^{2}e^{u_{0}}\mathrm{cosh}u_{0}}{2R_{\mathrm{pipe}}}\int\int_{\mathrm{solid}}dudv$$
$$\times [e^{-2u}-\mathrm{cos}2v],\qquad(3.9)$$

where we have used Eq. (2.14).

We now let  $Z \rightarrow \infty$  and cut off the integration over v where

$$y = c \cosh u_{\max} \cos v = Y$$
, or  $u_{\max} = \cosh^{-1} \frac{Y}{c \cos v} \gg 1$ .  
(3.10)

This leads to

$$\frac{Z_{\parallel}(k)}{Z_{0}} = \frac{jkc^{2}e^{u_{0}}\cosh u_{0}}{4\pi R_{\text{pipe}}} \int_{-\pi/2}^{\pi/2} dv \int_{u_{0}}^{u_{\text{max}}} du [e^{-2u} - \cos v]$$
$$\approx \frac{jkc^{2}e^{u_{0}}\cosh u_{0}}{4\pi R_{\text{pipe}}} \left[\frac{\pi}{2}e^{-2u_{0}} - \int_{-\pi/2}^{\pi/2} dv \cos 2v \right]$$
$$\times \left(\ln \frac{2Y}{c \cos v} - u_{0}\right), \qquad (3.11)$$

or

$$\frac{Z_{\parallel}(k)}{Z_0} = \frac{jkc^2 \cosh^2 u_0}{4R_{\text{pipe}}} = \frac{jkb^2}{4R_{\text{pipe}}},$$
(3.12)

where the last integral in Eq. (3.11) was done by parts for  $Y \ge c$ .

For a > b we need to modify our elliptical coordinates so that

$$y = c \sinh u \sin v, \quad z = c \cosh u \cos v,$$
$$a = c \cosh u_0, \quad b = c \sinh u_0, \quad c^2 = a^2 - b^2. \quad (3.13)$$

The matrix is unchanged, but now

$$\frac{\partial}{\partial y} = \frac{1}{D(u,v)} \left[ \frac{\cosh u \sin v}{c} \frac{\partial}{\partial u} + \frac{\sinh u \cos v}{c} \frac{\partial}{\partial v} \right].$$
(3.14)

This time one finds

$$\frac{Z_{\parallel}(k)}{Z_0} = \frac{jkc^2 \sinh^2 u_0}{4R_{\rm pipe}} = \frac{jkb^2}{4R_{\rm pipe}},$$
(3.15)

that is, the result is unchanged from Eq. (3.12), again depending only on the depth of the elliptical protrusion into the pipe and not on its width, as also found by Kurennoy [1].

## IV. SEMIELLIPTICAL EXTERIOR OBSTACLE—CAVITY

## A. Analytical approach

We now turn to the exterior semielliptical obstacle in Fig. 1(b). Here we need to choose appropriate potential forms for  $u \le u_0$ , and for  $u \ge u_0$ , and match them at  $u = u_0$ .

We again start with Eq. (2.15) and work with the complete set of solutions of the Laplace equation, namely,  $\cos nv \exp(\pm nu)$  and  $\sin nv \exp(\pm nu)$ . For  $u \ge u_0$  (and b > a), with the asymptotic field  $E_0$ , we choose

$$\Psi(u,v) = E_0 y - c E_0 \sum_{n=1}^{\infty} \alpha_n \cos nv \, e^{-nu} \qquad (4.1)$$

in order to satisfy the even symmetry about v=0 (z=0) and  $\Psi(u, \pm \pi/2)=0$  for  $u \ge u_0$ . If we write

$$\Psi(u_0, v) = cE_0 f(v), \qquad (4.2)$$

where f(v) is, as yet, an unknown function, we can solve for  $\alpha_n$  in terms of f(v) to obtain

$$\alpha_n = -\frac{2}{\pi} e^{nu_0} f_n + e^{u_0} \cosh u_0 \delta_{n1}, \qquad (4.3)$$

where

$$f_n \equiv \int_{-\pi/2}^{\pi/2} dv \cos nv f(v). \tag{4.4}$$

For  $u \leq u_0$ , we write

$$\Psi(u,v) = \sum_{m=1}^{\infty} \beta_n \cos nv \cosh mu \qquad (4.5)$$

for a potential which is well behaved within the ellipse. Recognizing in this case that f(v)=0 for  $\pi/2 < |v| < \pi$ , we solve for  $\beta_m$  in terms of f(v) to obtain

$$\beta_m = \frac{f_m}{\pi \ \cosh m u_0},\tag{4.6}$$

where  $f_m$  is consistent with the definition in Eq. (4.4). Both odd and even values of m must be included.

We now calculate the impedance as we did in the preceding section, this time including the regions  $u \ge u_0$ ,  $|v| \le \pi/2$ and  $u \le u_0$ ,  $|v| \le \pi$ . For  $u \ge u_0$  we find

$$\frac{Z_{\parallel}^{(>)}(k)}{Z_{0}} = -\frac{jkc^{2}}{4\pi R_{\text{pipe}}} \int \int_{\substack{u \ge u_{0} \\ y < Y}} du dv \sum_{\substack{n=1 \\ \text{odd}}}^{\infty} n \alpha_{n}$$
$$\times [e^{-(n-1)u} \cos(n+1)v \\ -e^{-(n+1)u} \cos(n-1)v]. \tag{4.7}$$

Clearly, only the terms with n=1 survive, leading ultimately to

$$\frac{Z_{\parallel}^{(>)}(k)}{Z_{0}} = \frac{jkc^{2}}{4R_{\text{pipe}}}\alpha_{1}e^{-u_{0}}\cosh u.$$
(4.8)

For  $u \le u_0$  we separate the two terms in Eq. (2.15). The second is simply

$$\frac{Z_{\parallel,2}^{(<)}(k)}{Z_0} = \frac{jkab}{\pi 4R_{\text{pipe}}} = \frac{jkc^2 \cosh u_0 \sinh u_0}{4R_{\text{pipe}}}.$$
 (4.9)

The first is

$$\frac{Z_{\parallel,1}^{(<)}(k)}{Z_0} = -\frac{jkc^2}{4\pi R_{\text{pipe}}} \int \int_{u \le u_0} du dv \sum_{m=1}^{\infty} m\beta_m$$
$$\times [\cosh(m+1)u\cos(m-1)v + \cosh(m-1)u\cos(m+1)v]. \tag{4.10}$$

Again, only the term m = 1 survives, and is

$$\frac{Z_{\parallel,1}^{(<)}(k)}{Z_0} = -\frac{jkc^2}{4R_{\text{pipe}}}\beta_1 \cosh u_0 \sinh u_0.$$
(4.11)

Using Eqs. (4.3) and (4.6) we have for the impedance

$$\frac{Z_{\parallel}(k)}{Z_0} = \frac{jk}{2R_{\text{pipe}}} \left[ \frac{b^2}{2} + ab - (a+b)^2 \frac{f_1}{\pi} e^{-u_0} \right].$$
 (4.12)

In order to find  $f_1$ , we must obtain and solve the integral equation which represents the match of  $\partial \Psi / \partial u$  at  $u = u_0$ ,  $|v| \le \pi/2$ . Here

$$\frac{\partial \Psi}{\partial u}\Big|_{u=u_{0^{+}}} = cE_{0} \left[ \sinh u_{0} \cos v + \sum_{\substack{n=1\\\text{odd}}}^{\infty} n \alpha_{n} e^{-nu_{0}} \cosh v \right]$$
(4.13)

and

$$\left. \frac{\partial \Psi}{\partial u} \right|_{u=u_0^-} = c E_0 \sum_{m=1}^\infty m \beta_m \mathrm{sinh} m u_0 \mathrm{cos} m v. \quad (4.14)$$

Equating Eqs. (4.13) and (4.14), and using Eqs. (4.3) and (4.6), we find

$$\int_{-\pi/2}^{\pi/2} dv' f(v') K(v,v') = \pi \cos v e^{u_0}, \qquad (4.15)$$

where

$$K(v,v') = \sum_{\substack{n=1 \\ \text{odd}}}^{\infty} (2 + \tanh nu_0) n \cos nv \cos uv'$$
$$+ \sum_{\substack{m=2 \\ \text{even}}}^{\infty} m \tanh nu_0 \cos nv \cos nv. \quad (4.16)$$

We now multiply Eq. (4.15) by  $\int_{-\pi/2}^{\pi/2} dv f(v)$  to obtain

$$\frac{\left[\int_{-\pi/2}^{\pi/2} dv f(v) \cos v\right]^{2}}{\int_{-\pi/2}^{\pi/2} dv f(v) \int_{-\pi/2}^{\pi/2} dv'} f(v') K(v,v') \\
= \frac{\int_{-\pi/2}^{\pi/2} dv f(v) \cos v}{\pi e^{u_{0}}} \\
= \frac{f_{1} e^{-u_{0}}}{\pi}.$$
(4.17)

This is a variational form for  $f_1$ , the only unknown parameter in Eq. (4.12) for the impedance. An accurate numerical value for  $Z_{\parallel}(k)/Z_0$  can be found by expanding f(v) into a complete set in the interval  $|v| \leq \pi/2$ , then truncating and solving the resulting matrix equations obtained by maximizing Eq. (4.17). We write

$$f(v) = \sum_{\substack{p=1 \\ \text{odd}}}^{P} c_p \sin\left(p\frac{\pi}{2}\right) \frac{\cos pv}{p}, \qquad (4.18)$$

truncated at p = P and normalize f(v) so that  $c_1 = 1$ . This leads to

$$\frac{f_1 e^{-u_0}}{\pi} = \left[ H_{11} + 2\sum_{\substack{p=3\\\text{odd}}}^P c_p H_{p1} + \sum_{\substack{p=3\\\text{odd}}}^P \sum_{\substack{q=3\\\text{odd}}}^P c_p c_q H_{pq} \right]^{-1},$$
(4.19)

where the symmetric matrix  $H_{pq}$  is

$$H_{pq} = H_{qp} = \frac{2 + \tanh p u_0}{P} \,\delta_{pq} + \frac{16}{\pi^2} \sum_{\substack{m=2\\ \text{even}}}^{\infty} \frac{m \tanh m u_0}{(m^2 - p^2)(m^2 - q^2)}.$$
(4.20)

Maximizing Eq. (4.19) with respect to the coefficients  $c_p$ ,  $p=3,5,\ldots,P$ , leads to

$$\frac{f_1 e^{-u_0}}{\pi} = \left[ H_{11} - \sum_{\substack{p=3\\\text{odd}}}^{P} \sum_{\substack{q=3\\\text{odd}}}^{P} H_{1p} (H^{-1})_{pq} H_{q1} \right]^{-1}.$$
(4.21)

Here  $(H^{-1})_{pq}$  is the inverse of the matrix  $H_{pq}$  with p and  $q=3,5,7,\ldots,P$ . This square matrix has the dimension

$$(P-1)/2$$
 by  $(P-1)/2$ . (4.22)

Note that

$$\tanh p u_0 = (1 - w^p) / (1 + w^p) \tag{4.23}$$

and

$$\tanh m u_0 = (1 - w^m) / (1 + w^m), \qquad (4.24)$$

with

$$w = (b-a)/(b+a).$$
 (4.25)

The final result for the impedance is given in Eq. (4.12), using Eqs. (4.20) and (4.21).

The analysis for an obstacle with a > b proceeds in a similar, but not identical pattern. The result is once again Eq. (4.12), using Eqs. (4.20) and (4.21), with only one change in Eq. (4.20):

## $\tanh p u_0 \rightarrow \coth p u_0$ ,

with  $\tanh u_0$  now being a/b instead of b/a. Thus w in Eq. (4.25) is replaced by -w in Eq. (4.23), but the use of  $\coth pu_0$  instead of  $\tanh pu_0$  for odd p leaves the expression for  $H_{pq}$  in terms of a and b unchanged. The same is true for the term  $\tanh mu_0$  in Eq. (4.24) since m is even. So the final expression in Eq. (4.12) is unchanged provided  $H_{pq}$  in Eqs. (4.20) and (4.21) is expressed in terms of a and b.

#### **B.** Variational approach—numerical results

We proceed with a numerical investigation of the variational scheme described by Eqs. (4.12)-(4.21). Truncating the sum in the denominator of Eq. (4.21) at different  $N=(P-1)/2=1,2,3,\ldots$ , we explore the scheme convergence, and compare the results for the impedance (4.12) with those obtained by other methods. In doing so, it is convenient to rewrite Eq. (4.12) in the form

$$\frac{Z_{\parallel}(k)}{Z_0} = \frac{jk}{2\pi R_{\rm pipe}} \frac{\pi ab}{2} F\left(\frac{a}{b}\right), \qquad (4.26)$$

where

$$F(x) = \frac{1}{x} + 2 - \frac{2(1/x + 2 + x)}{2 + x + 16s(x)/\pi^2 - \Sigma(x)}, \quad (4.27)$$

and

$$s(x) = \frac{1}{8} \sum_{n=1}^{\infty} \frac{n}{(n^2 - 1/4)^2} \frac{(1+x)^{2n} - (1-x)^{2n}}{(1+x)^{2n} + (1-x)^{2n}}.$$
(4.28)

Here  $\Sigma(x)$  denotes the sum in the denominator of Eq. (4.21) which is to be truncated.

The advantage of the representation (4.26) is that we know the asymptotic behavior of F(x) for two limiting cases. For  $x \ll 1$ , i.e., when  $a \ll b$ , but still  $b \ll R_{pipe}$  — a short and deep enlargement — it has been demonstrated in [8] that

$$F(x) \to 1 - \frac{4}{\pi^2} x.$$
 (4.29)

In this limit, the inductive impedance in Eq. (4.26) is mostly of magnetic origin: the beam magnetic field fills the cavity volume without being substantially perturbed, and therefore the inductance is simply proportional to the area of the obstacle cross section. A correction of the order of x=a/b to this term comes from the electric contribution. For a deep pillbox of depth *h* which is much larger than width *g*, the electric contribution was calculated in [8] by means of conformal mapping. It results in the electric term  $-g^2/(2\pi)$ , which is small compared to the magnetic one, equal to *hg* for such a pillbox. Obviously, the shape of a short and deep



FIG. 2. Function F(x) versus ellipse aspect ratio x=a/b. The solid curve is an interpolation of numerical results (thick points). The dashed lines show the asymptotic behavior Eqs. (4.29) and (4.30).

enlargement — rectangular or semielliptical — does not affect the electric term as long as  $g \ll h$ , since the beam electric field does not penetrate deeply into such a cavity, unlike the magnetic one. Substituting g = 2a into the electric term, and replacing the pillbox area hg by the semi-ellipse area  $\pi ab/2$  leads to the asymptotic form in Eq. (4.29).

The opposite limit,  $x \ge 1$ , corresponds to a very shallow cavity,  $b \le a$ . It has been shown for many particular shapes of such cavities (see [8], and references therein) that the low-frequency impedance of a small shallow cavity of the depth *h* and of an iris with the same cross section and having the same depth, are both inductive, equal to each other, and in the leading order are proportional to  $h^2$ . Since we already know the answer for a semielliptical iris (see Sec. III) we expect that for  $x \ge 1$ 

$$F(x) \to \frac{1}{x},\tag{4.30}$$

to match the low-frequency impedance of the shallow iris, given in Eq. (3.15).

The results of our numerical study are shown in Fig. 2, where the function F(x) is plotted against the ellipse aspect ratio x=a/b. The convergence of the variational scheme is rather fast for all values of x; in fact, results obtained with N=1 [i.e., when the matrix in the sum  $\Sigma(x)$  is truncated to merely a single number] and those for N=8, when the matrix has size  $8 \times 8$ , differ by less than 0.5%. And, of course, we can obtain the asymptotic value of F(x) for large N with much better accuracy, well below  $10^{-3}$ , simply by extrapolating the results for different matrix sizes at fixed x. Figure 2 also shows very good agreement with the expected asymptotic behavior Eq. (4.29) for small x and Eq. (4.30) for large x.

### **V. TRANSVERSE COUPLING IMPEDANCE**

We start with a dipole drive current for the transverse impedance in the form [9]

$$J_{z}(x,y,z;k) = I_{0} \delta(y) \exp(-jkz) [\delta(x-x_{1}) - \delta(x+x_{1})],$$
(5.1)

$$Z_{x}(k) = -\frac{1}{4kx_{1}^{2}|I_{0}|^{2}} \int dv \mathbf{E} \cdot \mathbf{J}^{*}, \qquad (5.2)$$

analogous to Eq. (2.1) for the longitudinal impedance. Using Maxwell's equations as we did in Sec. II, leads to

$$Z_{x}(k) = -\frac{1}{4kx_{1}^{2}|I_{0}|^{2}} \int_{S_{2} \neq S_{1}} dS_{z} \mathbf{n}_{2} \cdot \mathbf{E}_{1}^{*} \times \mathbf{H}_{2}, \quad (5.3)$$

but we must now use the form of  $\mathbf{E}_1$  (and  $\mathbf{H}_2$ ) appropriate to the source current in Eq. (4.26). In fact, we now have for  $\mathbf{E}_1$  and  $Z_0\mathbf{H}_1$  at the beam pipe wall

$$E_{1r} = Z_0 H_{1\phi} = \frac{2Z_0 I_0}{\pi R_{\text{pipe}}^2} x_1 \cos\phi \exp(-jkz),$$
  
$$E_{1\phi} = Z_0 H_{1r} = 0.$$
 (5.4)

As a result, we can write

$$\frac{Z_x(k)}{Z_0} \simeq -\frac{1}{2kx_1 I_0 Z_0 \pi R_{\text{pipe}}} \int d\phi \cos\phi \int dr (Z_0 H_{2\phi} e^{jkz}).$$
(5.5)

Once again we have written the impedance as an integral along the surface of the obstacle, where  $H_{2\phi}$  arises from the

driving field components  $E_{1r}$  and  $H_{1\phi}$  at the wall. Dropping the subscript 2, extracting the factor  $\cos\phi$  from  $H_{\phi}$ , and integrating over  $\phi$  leads to

$$\frac{Z_x(k)}{Z_0} \cong -\frac{1}{2kx_1 I_0 Z_0 R_{\text{pipe}}} \int dr (Z_0 H_{\phi} e^{jkz}).$$
(5.6)

We now write Eq. (5.6) as a double integral over drdz as we did in Sec. II, obtaining

$$\frac{Z_x(k)}{Z_0} = \frac{-j}{R_{\text{pipe}}^3} \int_{\text{solid}} dr \int dz \left(\frac{E_r - E_0}{E_0}\right), \quad (5.7)$$

where  $E_0$ , the maximum asymptotic field at the wall, is

$$E_0 = \frac{2Z_0 I_0}{\pi R_{\text{pipe}}^2} x_1.$$
 (5.8)

Comparison of Eq. (5.8) with Eq. (2.15) shows that the calculations for an exterior and an interior obstacle are exactly the same as they were for the longitudinal impedance. In fact, the results for the transverse impedance can be obtained simply by multiplying the results for the longitudinal impedance in Eqs. (3.12), (3.15), (4.12), and (4.21) by  $2/kR_{pipe}^2$ .

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